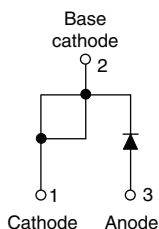


Fast Soft Recovery Rectifier Diode, 20 A



TO-220AC



FEATURES/DESCRIPTION

The 20ETF.. fast soft recovery rectifier series has been optimized for combined short reverse recovery time and low forward voltage drop.

The glass passivation ensures stable reliable operation in the most severe temperature and power cycling conditions.

This product series has been designed and qualified for industrial level.

PRODUCT SUMMARY

V_F at 20 A	< 1.31 V
I_{FSM}	355 A
V_{RRM}	800 to 1200 V

APPLICATIONS

- Output rectification and freewheeling in inverters, choppers and converters
- Input rectifications where severe restrictions on conducted EMI should be met

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	VALUES	UNITS
V_{RRM}		800 to 1200	V
$I_{F(AV)}$	Sinusoidal waveform	20	A
I_{FSM}		355	
t_{rr}	1 A, 100 A/ μ s	95	ns
V_F	20 A, $T_J = 25^\circ\text{C}$	1.31	V
T_J	Range	- 40 to 150	$^\circ\text{C}$

VOLTAGE RATINGS

PART NUMBER	V_{RRM} , MAXIMUM PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} AT 150 $^\circ\text{C}$ mA
20ETF08	800	900	6
20ETF10	1000	1100	
20ETF12	1200	1300	

ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum average forward current	$I_{F(AV)}$	$T_C = 97^\circ\text{C}$, 180° conduction half sine wave	20	A
Maximum peak one cycle non-repetitive surge current	I_{FSM}	10 ms sine pulse, rated V_{RRM} applied	300	
		10 ms sine pulse, no voltage reapplied	355	
Maximum I^2t for fusing	I^2t	10 ms sine pulse, rated V_{RRM} applied	450	A^2s
		10 ms sine pulse, no voltage reapplied	635	
Maximum $I^2\sqrt{t}$ for fusing	$I^2\sqrt{t}$	$t = 0.1$ to 10 ms, no voltage reapplied	6350	$\text{A}^2\sqrt{\text{s}}$

20ETF.. Soft Recovery Series

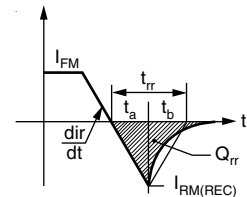
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Fast Soft Recovery
Rectifier Diode, 20 A



ELECTRICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS		VALUES	UNITS
Maximum forward voltage drop	V _{FM}	20 A, T _J = 25 °C		1.31	V
Forward slope resistance	r _t	T _J = 150 °C		11.88	mΩ
Threshold voltage	V _{F(TO)}			0.93	V
Maximum reverse leakage current	I _{RM}	T _J = 25 °C	V _R = Rated V _{RRM}	0.1	mA
		T _J = 150 °C		6	

RECOVERY CHARACTERISTICS				
PARAMETER	SYMBOL	TEST CONDITIONS	VALUES	UNITS
Reverse recovery time	t_{rr}	I_F at 20 Apk 25 A/ μs 25 $^{\circ}\text{C}$	400	ns
Reverse recovery current	I_{rr}		6.1	A
Reverse recovery charge	Q_{rr}		1.7	μC
Snap factor	S	Typical	0.6	



THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 40 to 150	°C
Maximum thermal resistance, junction to case		R _{thJC}	DC operation	0.9	°C/W
Maximum thermal resistance, junction to ambient		R _{thJA}		62	
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5	
Approximate weight				2	g
				0.07	oz.
Mounting torque	minimum			6 (5)	kgf · cm (lbf · in)
	maximum			12 (10)	
Marking device		Case style TO-220AC	20ETF08		
			20ETF10		
			20ETF12		



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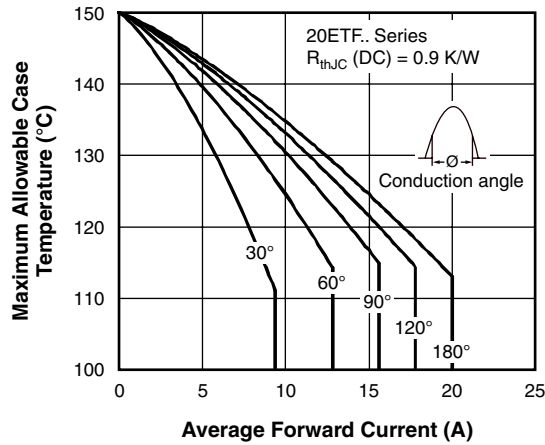


Fig. 1 - Current Rating Characteristics

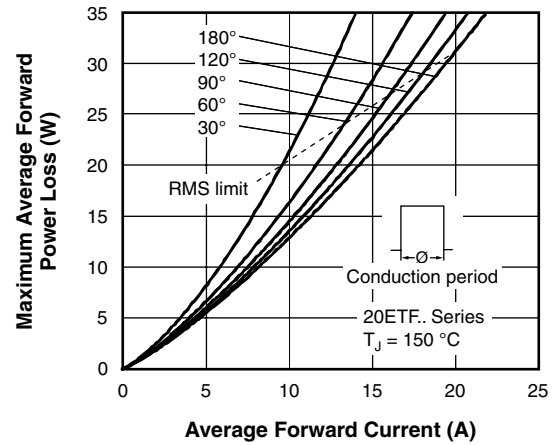


Fig. 4 - Forward Power Loss Characteristics

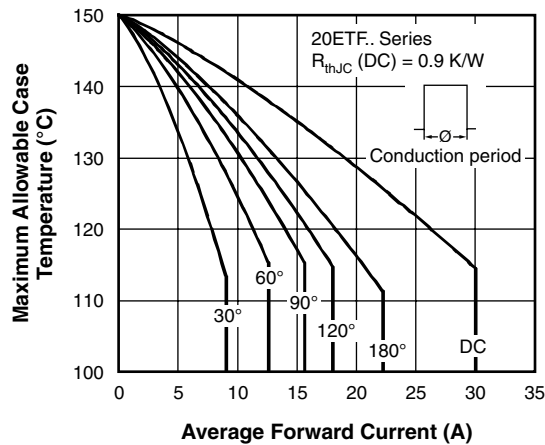


Fig. 2 - Current Rating Characteristics

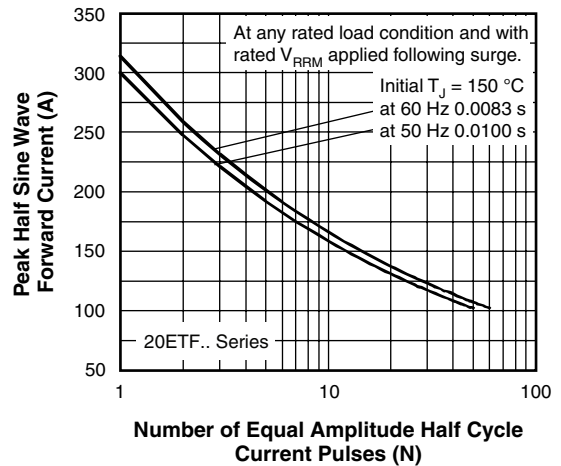


Fig. 5 - Maximum Non-Repetitive Surge Current

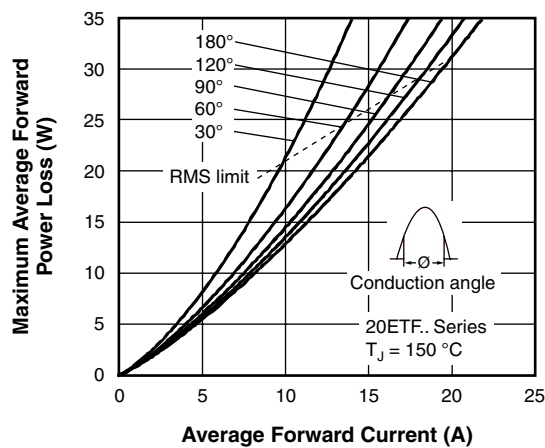


Fig. 3 - Forward Power Loss Characteristics

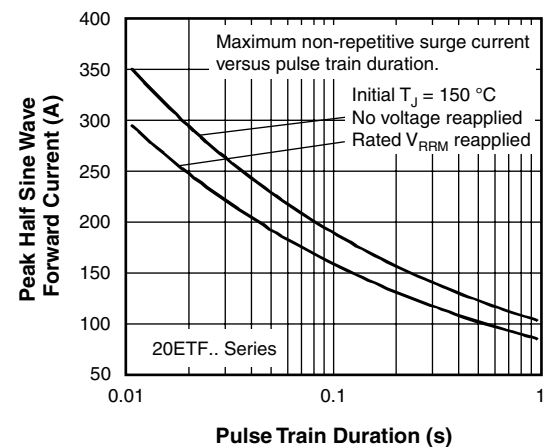


Fig. 6 - Maximum Non-Repetitive Surge Current

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Rectifier Diode, 20 A

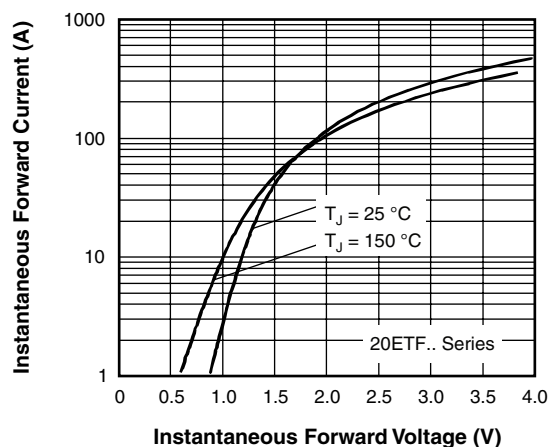


Fig. 7 - Forward Voltage Drop Characteristics

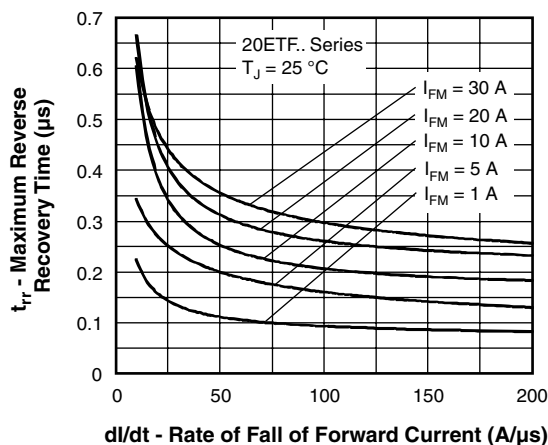


Fig. 8 - Recovery Time Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

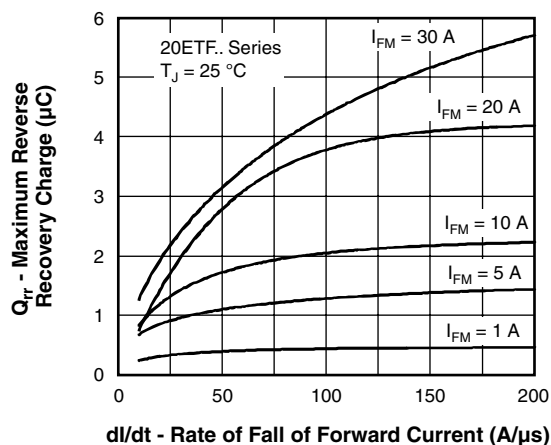


Fig. 10 - Recovery Charge Characteristics, $T_J = 25\text{ }^{\circ}\text{C}$

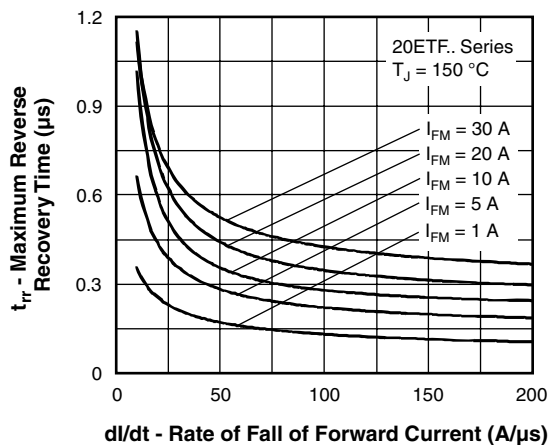


Fig. 9 - Recovery Time Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$

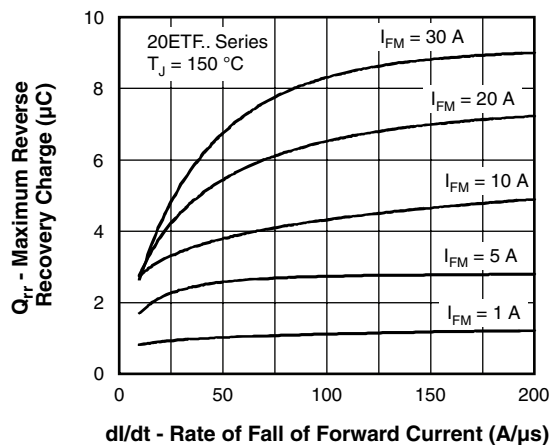


Fig. 11 - Recovery Charge Characteristics, $T_J = 150\text{ }^{\circ}\text{C}$



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Fast Soft Recovery
Rectifier Diode, 20 A

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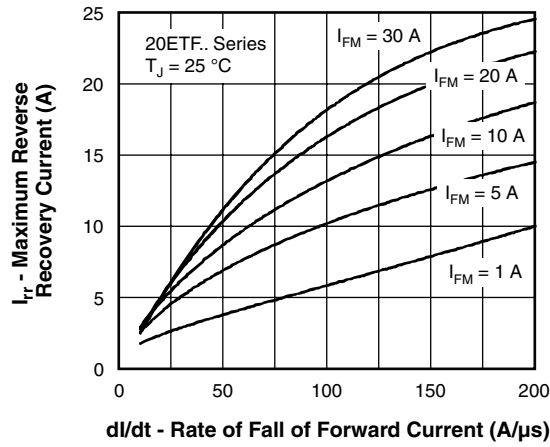


Fig. 12 - Recovery Current Characteristics, $T_J = 25^\circ C$

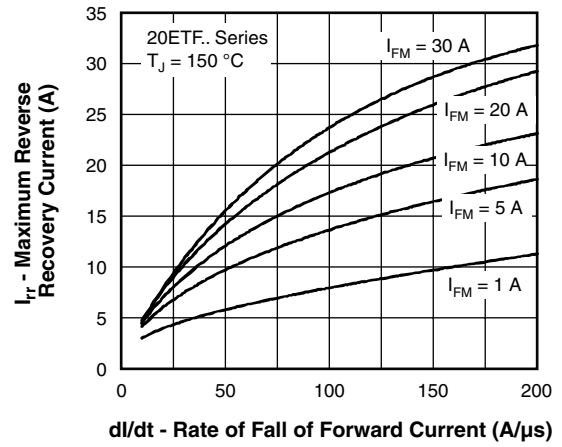


Fig. 13 - Recovery Current Characteristics, $T_J = 150^\circ C$

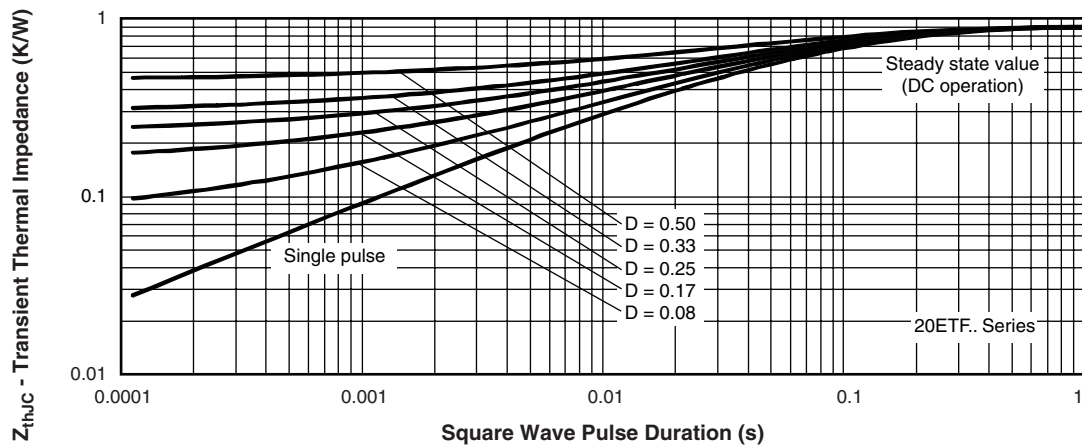


Fig. 14 - Thermal Impedance Z_{thJC} Characteristics

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**Device code**

20	E	T	F	12	-
1	2	3	4	5	6

- 1 - Current rating ($20 = 20\text{ A}$)
- 2 - Circuit configuration:
E = Single diode
- 3 - Package:
T = TO-220AC
- 4 - Type of silicon:
F = Fast soft recovery rectifier
- 5 - Voltage ratings _____
- 6 -
 - None = Standard production
 - PbF = Lead (Pb)-free

08 = 800 V
10 = 1000 V
12 = 1200 V

Dimensions	http://www.vishay.com/doc?95221
Part marking information	http://www.vishay.com/doc?95224



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